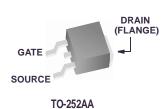
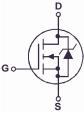


• UIS Capability (Single Pulse and Repetitive Pulse)

#### Formerly developmental type 82760





## MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

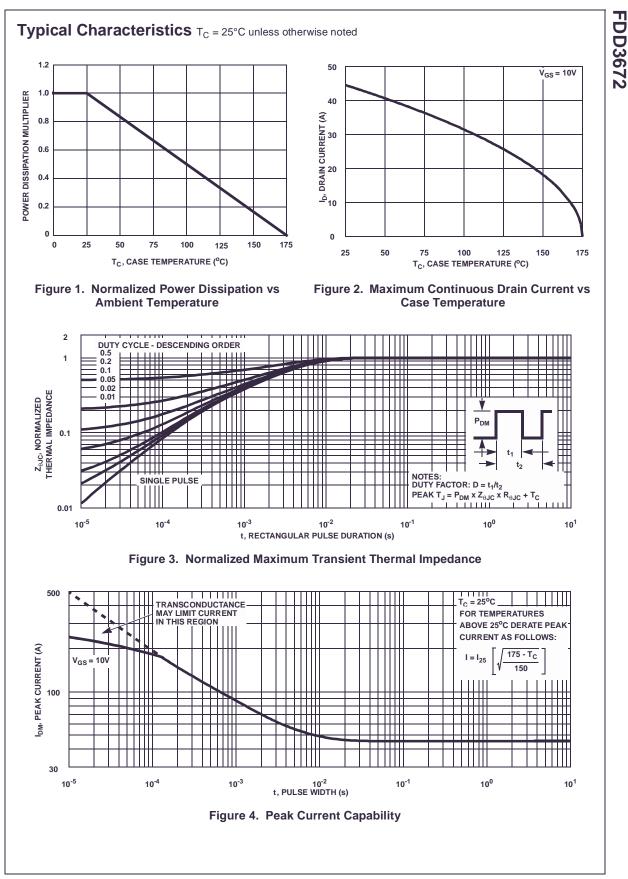
Symbol	Parameter	Ratings	Units	
V <sub>DSS</sub>	Drain to Source Voltage	100	V	
V <sub>GS</sub>	Gate to Source Voltage	±20	V	
I <sub>D</sub>	Drain Current			
	Continuous ( $T_C = 25^{\circ}C$ , $V_{GS} = 10V$ )	44	A	
	Continuous ( $T_C = 100^{\circ}C$ , $V_{GS} = 10V$ )	31	A	
	Continuous ( $T_{amb} = 25^{\circ}C$ , $V_{GS} = 10V$ , $R_{\theta JA} = 52^{\circ}C/W$ )	6.5	A	
	Pulsed	Figure 4	A	
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)	120	mJ	
P <sub>D</sub>	Power dissipation	135	W	
	Derate above 25°C	0.9	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature	-55 to 175	°C	

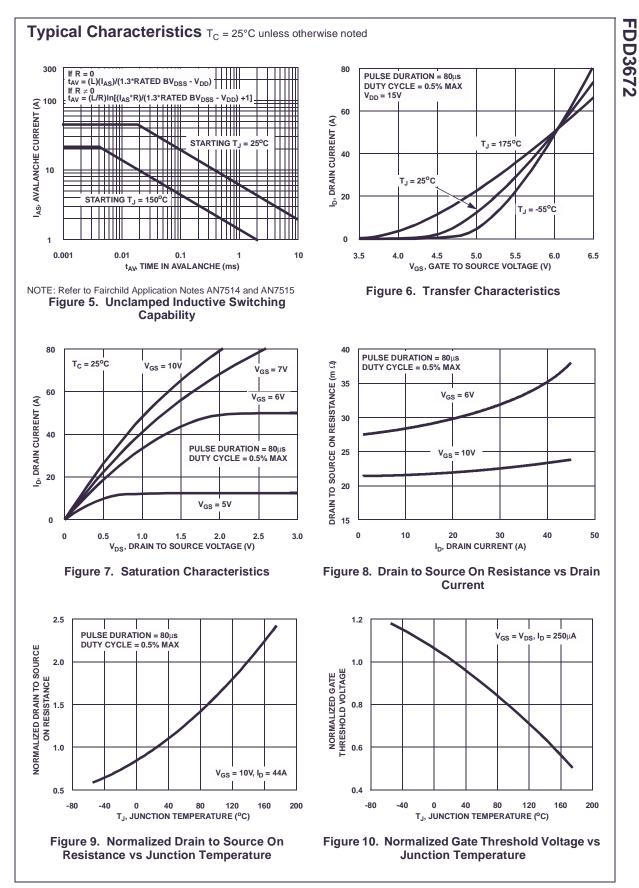
### **Thermal Characteristics**

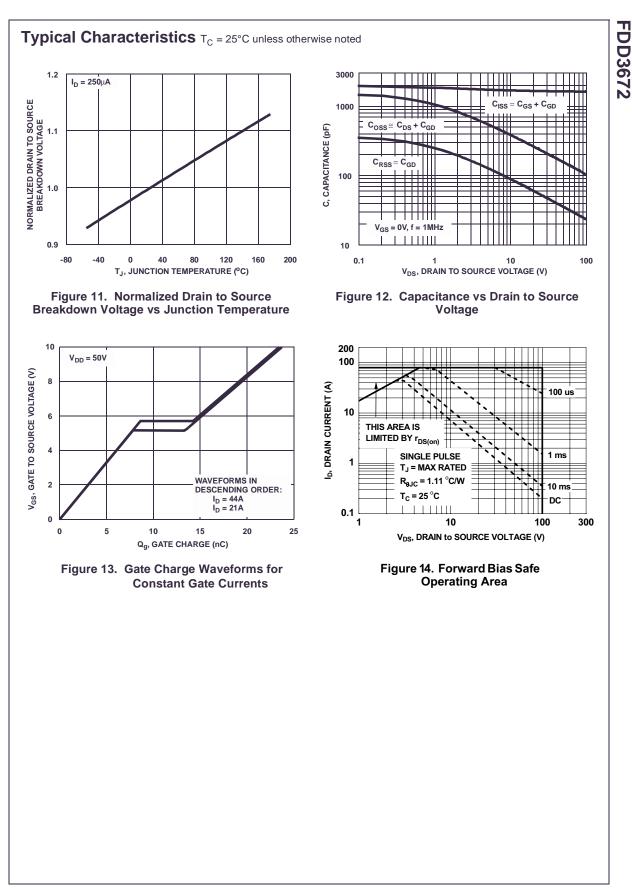
$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case TO-252	1.11	°C/W
$R_{\thetaJA}$	Thermal Resistance Junction to Ambient TO-252	100	°C/W
$R_{\thetaJA}$	Thermal Resistance Junction to Ambient TO-252, 1in <sup>2</sup> copper pad area	52	°C/W

#### Reliability data can be found at: http://www.fairchildsemi.com/products/discrete/reliability/index.html. All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

FDD3	Marking	Device	Package	Reel Size	Таре	Width	Qua	ntity
FDD3672 FDD3672			TO-252AA			mm	2500 units	
Electric	al Chara	icteristics T <sub>C</sub> = 25°0	C unless otherwise	noted				
Symbol		Parameter	Test C	onditions	Min	Тур	Мах	Units
Off Chara	cteristics							
B <sub>VDSS</sub>	Drain to So	ource Breakdown Voltage	I <sub>D</sub> = 250μA, V	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V		-	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current		V <sub>DS</sub> = 80V	V <sub>DS</sub> = 80V		-	1	μA
			$V_{GS} = 0V$	T <sub>C</sub> = 150°C	-	-	250	•
IGSS	Gate to So	urce Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Chara	cteristics							
V <sub>GS(TH)</sub>	Gate to So	urce Threshold Voltage	$V_{GS} = V_{DS}, I$	<sub>D</sub> = 250μA	2	-	4	V
			I <sub>D</sub> = 44A, V <sub>G</sub>	<sub>S</sub> = 10V	-	0.024	0.028	
r <sub>DS(ON)</sub>	Drain to So	ource On Resistance	$I_D = 21A, V_G$		-	0.031	0.047	Ω
			I <sub>D</sub> =44A, V <sub>GS</sub>	=10V, T <sub>C</sub> =175°C	-	0.054	0.068	
Dynamic	Character	ristics						
C <sub>ISS</sub>	Input Capa				-	1710	-	pF
C <sub>OSS</sub>	Output Cap		V <sub>DS</sub> = 25V, \	$V_{\rm GS} = 0V,$	-	247	-	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		f = 1MHz		-	62	-	pF
Q <sub>g(TOT)</sub>		Charge at 10V	$V_{GS} = 0V$ to	10V	-	24	36	nC
Q <sub>g(TH)</sub>	Threshold Gate Charge		$V_{GS} = 0V$ to 2		-	3	4.5	nC
Q <sub>gs</sub>	_	urce Gate Charge		$I_D = 44A$	-	8.6	-	nC
Q <sub>gs2</sub>	Gate Char	ge Threshold to Plateau		$I_g = 1.0 \text{mA}$	-	5.6	-	nC
Q <sub>gd</sub>	Gate to Dra	ain "Miller" Charge			-	5.6	-	nC
Resistive	Switching	g Characteristics (\	/ <sub>GS</sub> = 10V)					
t <sub>ON</sub>	Turn-On Ti	-			-	-	104	ns
t <sub>d(ON)</sub>	Turn-On D	elay Time			-	11	-	ns
t <sub>r</sub>	Rise Time		V <sub>DD</sub> = 50V, I <sub>I</sub>	= 44A	-	59	-	ns
t <sub>d(OFF)</sub>	Turn-Off De	Turn-Off Delay Time $V_{GS} = 10V, R_{GS} = 11.0\Omega$			-	26	-	ns
t <sub>f</sub>	Fall Time				-	44	-	ns
t <sub>OFF</sub>	Turn-Off Ti	me		-		-	104	ns
	urce Diod	e Characteristics						
Drain-Soເ			I <sub>SD</sub> = 44A		-	-	1.25	V
	Course to I				-	-	1.0	V
<b>Drain-Soเ</b> V <sub>SD</sub>	Source to I	Drain Diode Voltage	$I_{SD} = 21A$					
	Reverse R	ecovery Time ecovery Charge	I <sub>SD</sub> = 44A, dl	<sub>SD</sub> /dt =100A/μs <sub>SD</sub> /dt =100A/μs	-	-	52	ns

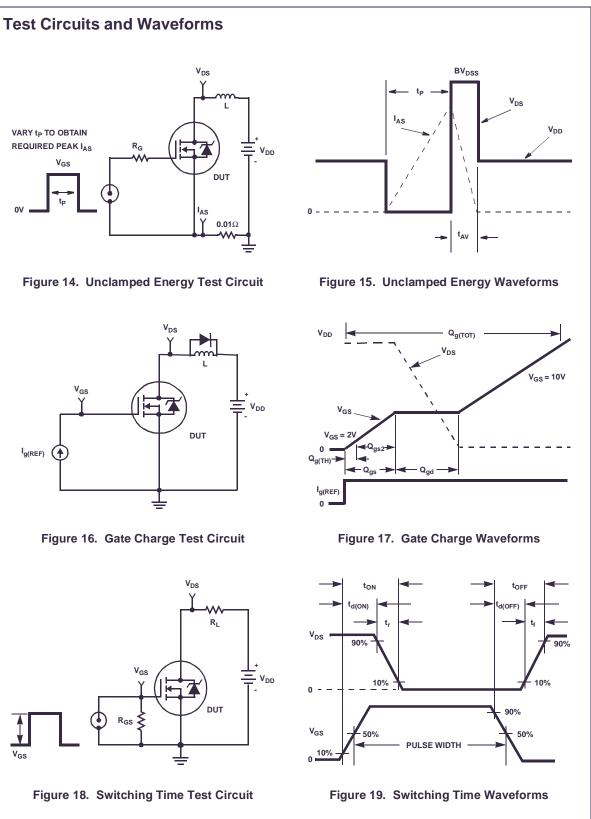






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FDD3672 Rev. 1.2



Ig(REF)

### Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature,  $T_{JM}$ , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation,  $P_{DM}$ , in an application. Therefore the application's ambient temperature,  $T_A$  (°C), and thermal resistance  $R_{\theta JA}$  (°C/W) must be reviewed to ensure that  $T_{JM}$  is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-252 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of  $P_{DM}$  is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 20 defines the  $R_{\theta,JA}$  for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

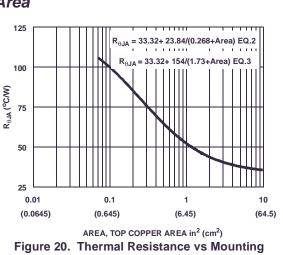
Thermal resistances corresponding to other copper areas can be obtained from Figure 20 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

$$R_{\Theta JA} = 33.32 + \frac{23.84}{(0.268 + Area)}$$
(EQ. 2)

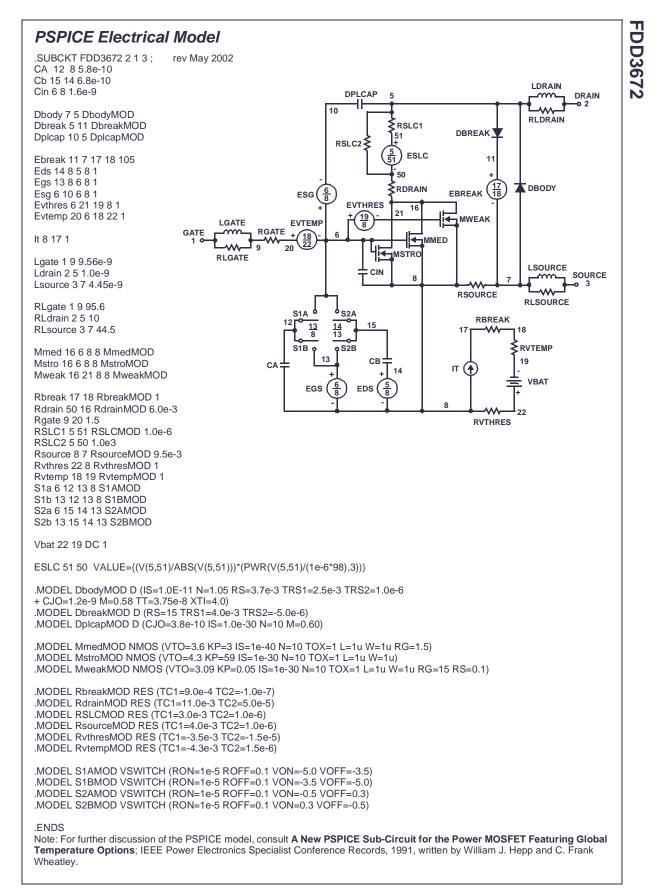
Area in Inches Squared

$$R_{\theta JA} = 33.32 + \frac{154}{(1.73 + Area)}$$
(EQ. 3)

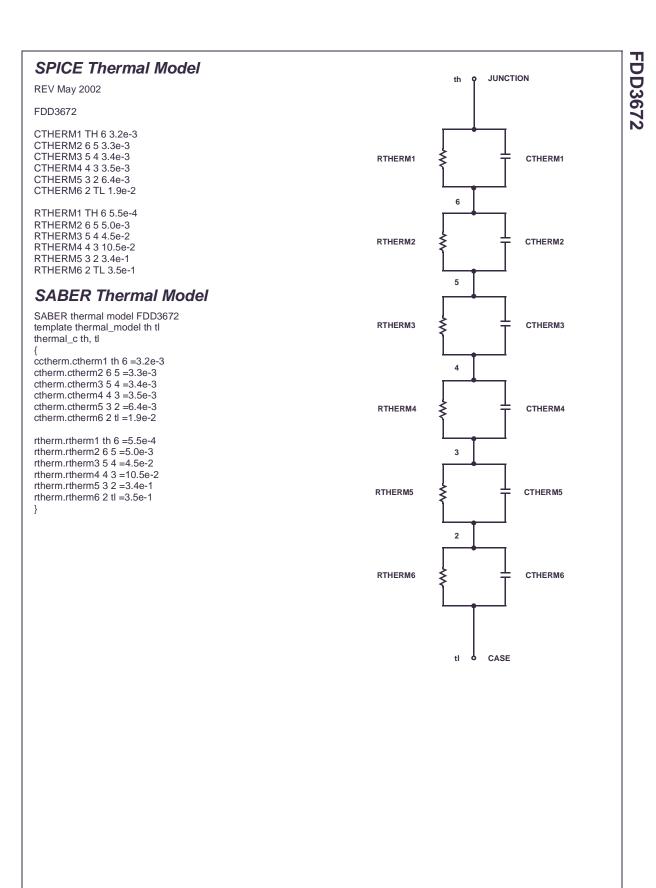
Area in Centimeters Squared







#### SABER Electrical Model REV May 2002 template FDD3672 n2,n1,n3 electrical n2,n1,n3 var i iscl dp..model dbodymod = (isl=1.0e-11,nl=1.05,rs=3.7e-3,trs1=2.5e-3,trs2=1.0e-6,cjo=1.2e-9,m=0.58,tt=3.75e-8,xti=4.0) dp..model dbreakmod = (rs=15.trs1=4.0e-3.trs2=-5.0e-6)dp..model dplcapmod = (cjo=3.8e-10,isl=10.0e-30,nl=10,m=0.60) m..model mmedmod = (type=\_n,vto=3.6,kp=3,is=1e-40, tox=1) m..model mstrongmod = (type=\_n,vto=4.3,kp=59,is=1e-30, tox=1) m.model mstrongmod = $(type=_n, vto=3.09, kp=0.05, is=1e-30, tox=1, rs=0.1)$ m.model mweakmod = $(type=_n, vto=3.09, kp=0.05, is=1e-30, tox=1, rs=0.1)$ LDRAIN DRAIN sw\_vcsp..model s1amod = (ron=1e-5,roff=0.1,von=-5.0,voff=-3.5) 5 m-11 02 sw\_vcsp..model s1bmod = (ron=1e-5,roff=0.1,von=-3.5,voff=-5.0) 10 RLDRAIN sw\_vcsp..model s2amod = (ron=1e-5,roff=0.1,von=-0.5,voff=0.3) **₹**RSLC1 sw\_vcsp..model s2bmod = (ron=1e-5,roff=0.1,von=0.3,voff=-0.5) 51 RSLC2 ₹ c.ca n12 n8 = 5.8e-10c.cb n15 n14 = 6.8e-10 Ð ISCI c.cin n6 n8 = 1.6e-9DBREAK 50 dp.dbody n7 n5 = model=dbodymod ≷rdrain 6 8 FSG 11 dp.dbreak n5 n11 = model=dbreakmod T DBODY EVTHRES 16 dp.dplcap n10 n5 = model=dplcapmod 21 (<u>19</u>) 8 4 MWFAK LGATE EVTEMP RGATE spe.ebreak n11 n7 n17 n18 = 105 GATE m+ / 18 22 EBREAK . spe.eds n14 n8 n5 n8 = 1 ~~~ 9 20 spe.egs n13 n8 n6 n8 = 1 RLGATE spe.esg n6 n10 n6 n8 = 1 LSOURCE CIN SOURCE 8 spe.evthres n6 n21 n19 n8 = 1 3 0 spe.evtemp n20 n6 n18 n22 = 1 RSOURCE ᄿ RLSOURCE i.it n8 n17 = 1 S1A S2A RBREAK <u>13</u> 8 <u>14</u> 13 15 17 18 l.lgate n1 n9 = 95.6e-9 I.ldrain n2 n5 = 1.0e-9 RVTEMP S1B o S2B l.lsource n3 n7 = 4.45e-9 13 св 19 CA IT 14 res.rlgate n1 n9 = 9.56 VBAT 6 5 EGS EDS res.rldrain n2 n5 = 10 res.rlsource n3 n7 = 44.5 8 22 RVTHRES m.mmed n16 n6 n8 n8 = model=mmedmod, l=1u, w=1u m.mstrong n16 n6 n8 n8 = model=mstrongmod, l=1u, w=1u m.mweak n16 n21 n8 n8 = model=mweakmod, l=1u, w=1u res.rbreak n17 n18 = 1, tc1=9.0e-4,tc2=-1.0e-7 res.rdrain n50 n16 = 6.0e-3, tc1=11.0e-3,tc2=5.0e-5 res.rgate n9 n20 = 1.5res.rslc1 n5 n51 = 1.0e-6, tc1=3.0e-3,tc2=1.0e-6 res.rslc2 n5 n50 = 1.0e3 res.rsource n8 n7 = 9.5e-3, tc1=4.0e-3,tc2=1.0e-6 res.rvthres n22 n8 = 1, tc1=-3.5e-3,tc2=-1.5e-5 res.rvtemp n18 n19 = 1, tc1=-4.3e-3,tc2=1.5e-6 sw vcsp.s1a n6 n12 n13 n8 = model=s1amod sw\_vcsp.s1b n13 n12 n13 n8 = model=s1bmod sw\_vcsp.s2a n6 n15 n14 n13 = model=s2amod sw\_vcsp.s2b n13 n15 n14 n13 = model=s2bmod v.vbat n22 n19 = dc=1 equations { i (n51->n50) +=iscl iscl: v(n51,n50) = ((v(n5,n51)/(1e-9+abs(v(n5,n51))))\*((abs(v(n5,n51)\*1e6/98))\*\* 3))



DD3672

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